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MOSFET - Power, Single N-Channel

80 V, 9.4 mΩ, 64 A NVMFS6H848N

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- NVMFS6H848NWF Wettable Flank Option for Enhanced Optical Inspection
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halide Free, and are RoHS Compliant

| MAXIMUM RATINGS | $(I_{\rm J} = 25^{\circ})$ | J unless otherw | /ise noted) | | | |
|-------------------------------------------------------------------------------|---------------------------------------|------------------------|-----------------------------------|----------------|------|--|
| Parameter | | | Symbol | Value | Unit | |
| Drain-to-Source Voltage | | | V _{DSS} | 80 | V | |
| Gate-to-Source Voltage | | | V _{GS} | ±20 | V | |
| Continuous Drain | Steady State | $T_{C} = 25^{\circ}C$ | Ι _D | 57 | А | |
| Current R _{θJC} (Notes 1, 3) | Siale | T _C = 100°C | | 40 | | |
| Power Dissipation | | T _C = 25°C | PD | 73 | W | |
| R _{θJC} (Note 1) | | T _C = 100°C | | 37 | | |
| Continuous Drain | Steady State | $T_A = 25^{\circ}C$ | ۱ _D | 13 | А | |
| Current R _{θJA} (Notes 1, 2, 3) | Sidle | T _A = 100°C | | 9.0 | | |
| Power Dissipation | | $T_A = 25^{\circ}C$ | PD | 3.7 | W | |
| R _{θJA} (Notes 1, 2) | | T _A = 100°C | | 1.8 |] | |
| Pulsed Drain Current | $T_A = 25^{\circ}C, t_p = 10 \ \mu s$ | | I _{DM} | 308 | А | |
| Operating Junction and Storage Temperature Range | | | T _J , T _{stg} | –55 to +175 | °C | |
| Source Current (Body Diode) | | | ۱ _S | 61 | А | |
| Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 8.2 A) | | | E _{AS} | 278 | mJ | |
| Lead Temperature for Soldering Purposes (1/8" from case for 10 s) | | | ΤL | 260 | °C | |

MAXIMUM RATINGS (T₁ = 25°C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

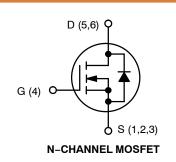
| Parameter | Symbol | Value | Unit |
|---------------------------------------------|-----------------|-------|------|
| Junction-to-Case - Steady State | $R_{\theta JC}$ | 2.0 | °C/W |
| Junction-to-Ambient - Steady State (Note 2) | $R_{\theta JA}$ | 41 | |

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

| V _{(BR)DSS} | R _{DS(ON)} MAX | I _D MAX |
|----------------------|-------------------------|--------------------|
| 80 V | 9.4 mΩ @ 10 V | 64 A |

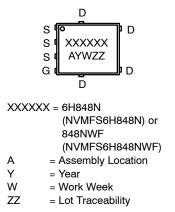




DFN5 (SO-8FL) CASE 488AA STYLE 1 DFNW5 5x6

(FULL-CUT SO8FL WF) CASE 507BA

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

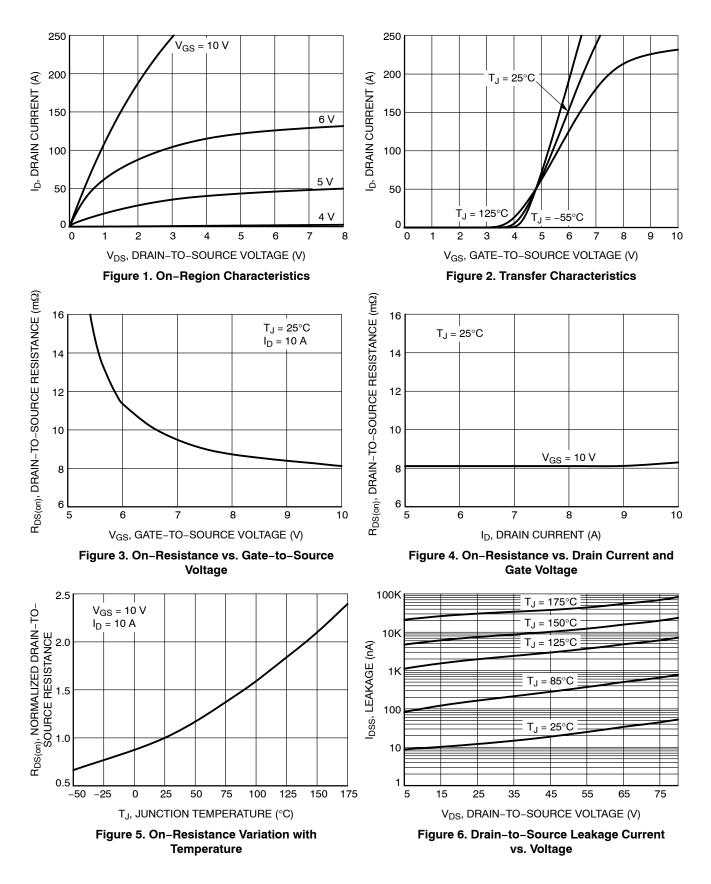
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

| Parameter | Symbol | Test Condition | | Min | Тур | Max | Unit |
|--------------------------------------------------------------|------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------|-----|------|-----|-------|
| OFF CHARACTERISTICS | - | | | | | | |
| Drain-to-Source Breakdown Voltage | V _{(BR)DSS} | V _{GS} = 0 V, I _D = 250 μA 80 | | 80 | | | V |
| Drain-to-Source Breakdown Voltage Temperature Coefficient | V _{(BR)DSS} / T _J | | | | 39 | | mV/°C |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{GS} = 0 V, \\ V_{DS} = 80 V \\ \hline T_{J} = 125^{\circ}C \\ \hline T_{J} = 125^{\circ}$ | | | | 10 | μΑ |
| | | | | | | 100 | |
| Gate-to-Source Leakage Current | I _{GSS} | V _{DS} = 0 V, V _{GS} = 20 V | | | | 100 | nA |
| ON CHARACTERISTICS (Note 4) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | $V_{GS} = V_{DS}, \ I_D = 70$ | μΑ | 2.0 | | 4.0 | V |
| Threshold Temperature Coefficient | V _{GS(TH)} /T _J | 1 | | | -7.3 | | mV/°C |
| Drain-to-Source On Resistance | R _{DS(on)} | V _{GS} = 10 V | I _D = 10 A | | 8.1 | 9.4 | mΩ |
| Forward Transconductance | 9FS | V _{DS} = 15 V, I _D = 20 A | | | 52 | | S |
| CHARGES, CAPACITANCES & GATE R | ESISTANCE | | | | | | |
| Input Capacitance | C _{ISS} | V _{GS} = 0 V, f = 1 MHz, V _{DS} = 40 V | | | 1180 | | pF |
| Output Capacitance | C _{OSS} | | | | 170 | | |
| Reverse Transfer Capacitance | C _{RSS} | | | | 8.0 | | |
| Total Gate Charge | Q _{G(TOT)} | V_{GS} = 10 V, V_{DS} = 40 V; I_D = 20 A | | | 16 | | nC |
| Threshold Gate Charge | Q _{G(TH)} | V _{GS} = 10 V, V _{DS} = 40 V; I _D = 20 A | | | 3.1 | | 1 |
| Gate-to-Source Charge | Q _{GS} | | | | 4.8 | | 1 |
| Gate-to-Drain Charge | Q _{GD} | | | | 2.8 | | 1 |
| Plateau Voltage | V _{GP} | | | | 4.5 | | V |
| SWITCHING CHARACTERISTICS (Note | 5) | | | | | | |
| Turn-On Delay Time | t _{d(ON)} | $V_{GS} = 10 \text{ V}, V_{DS} = 64 \text{ V},$ $I_D = 20 \text{ A}, R_G = 2.5 \Omega$ | | | 13 | | ns |
| Rise Time | t _r | | | | 33 | | - |
| Turn-Off Delay Time | t _{d(OFF)} | | | | 34 | | |
| Fall Time | t _f | | | | 23 | | |
| DRAIN-SOURCE DIODE CHARACTERI | STICS | | | | • | | • |
| Forward Diode Voltage | V _{SD} | V _{GS} = 0 V, I _S = 10 A | T _J = 25°C | | 0.8 | 1.2 | V |
| | | | T _J = 125°C | | 0.7 | | |
| Reverse Recovery Time | t _{RR} | V _{GS} = 0 V, dIS/dt = 100 A/µs, I _S = 20 A | | | 39 | | ns |
| Charge Time | t _a | | | | 25 | | 1 |
| Discharge Time | t _b | | | | 14 | | 1 |
| Reverse Recovery Charge | Q _{RR} | | | | 41 | | nC |

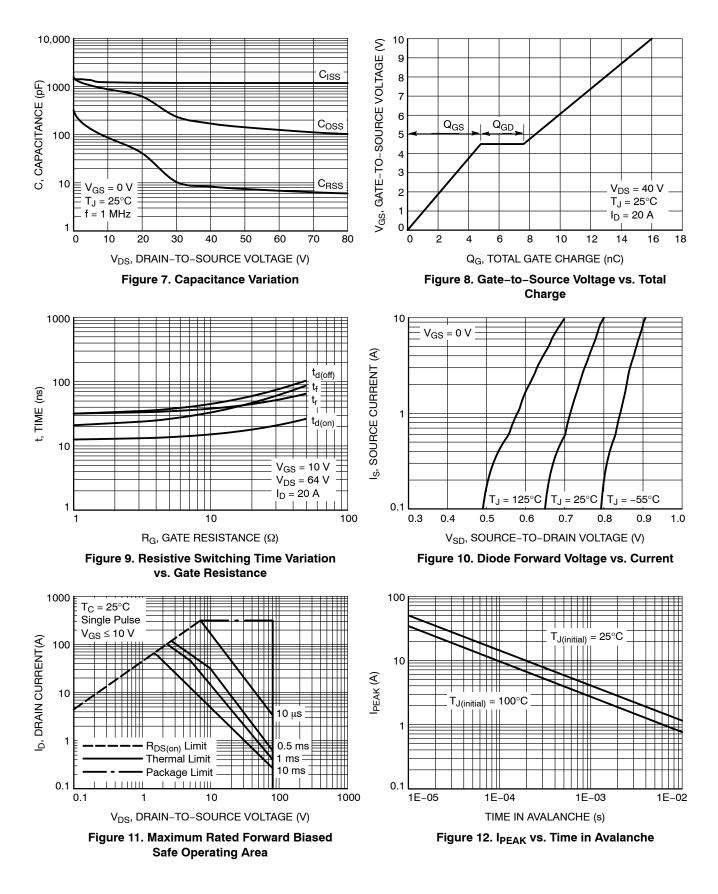
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%.

5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (continued)



TYPICAL CHARACTERISTICS (continued)

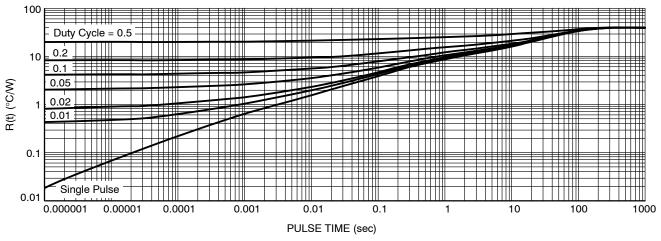


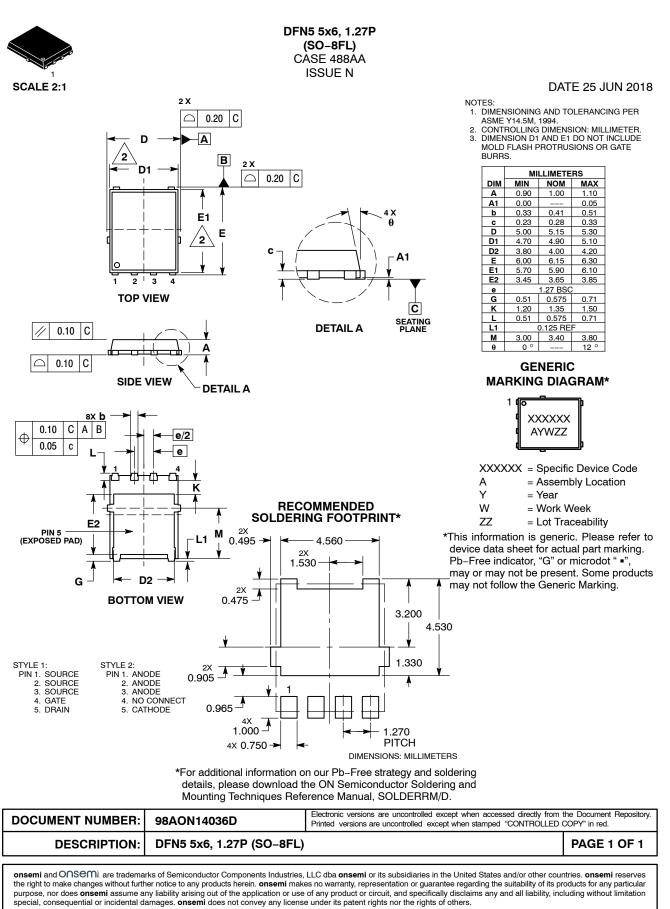
Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] |
|------------------|---------|--------------------------------------------------|-----------------------|
| NVMFS6H848NT1G | 6H848N | DFN5 (Pb-Free, Halide Free) | 1500 / Tape & Reel |
| NVMFS6H848NWFT1G | 848NWF | DFNW5 (Pb-Free, Halide Free, Wettable Flanks) | 1500 / Tape & Reel |

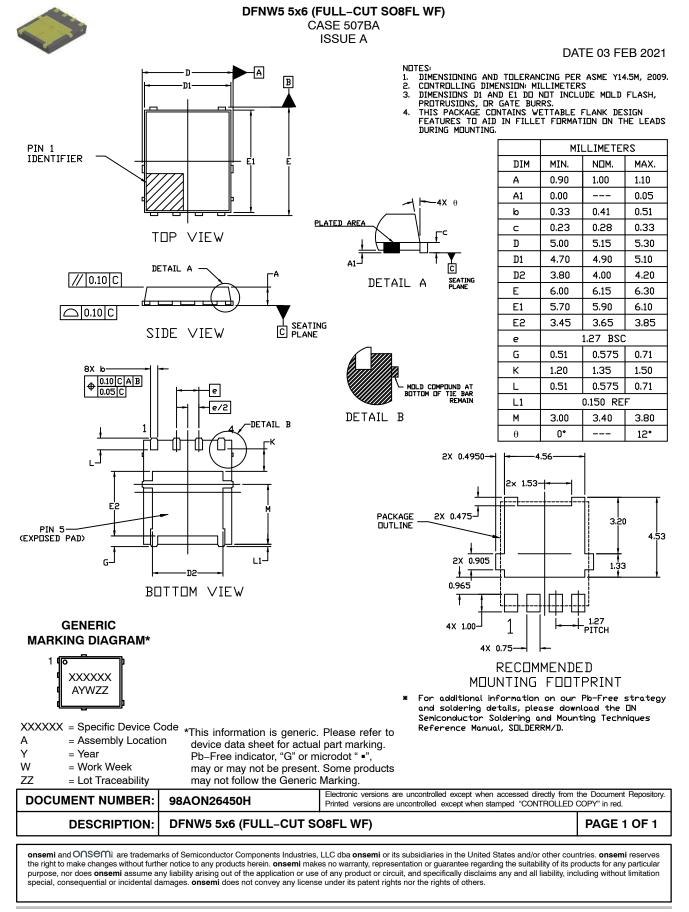
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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